

Surface Mount General Purpose Silicon Rectifiers

Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

PIN	DESCRIPTION
1	Cathode
2	Anode



Simplified outline SOD-123 and symbol

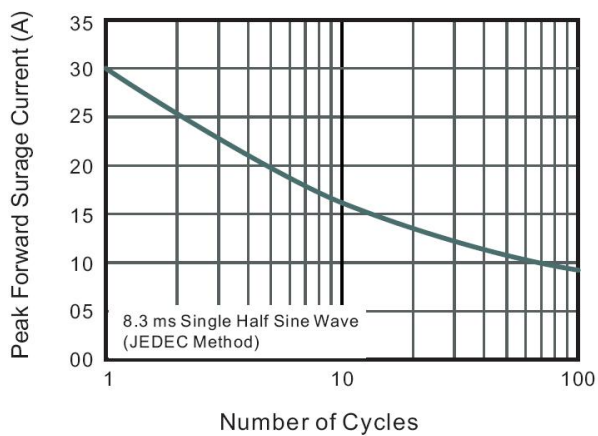
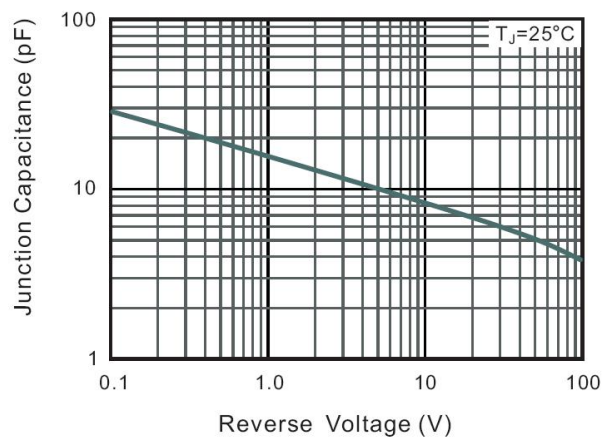
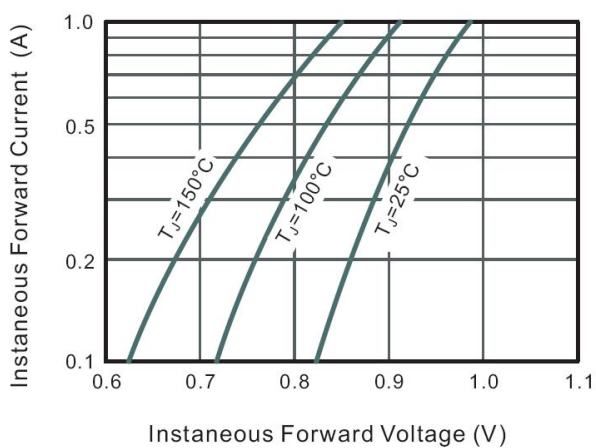
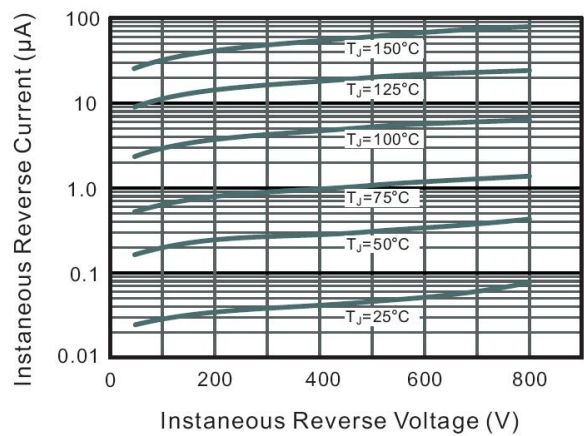
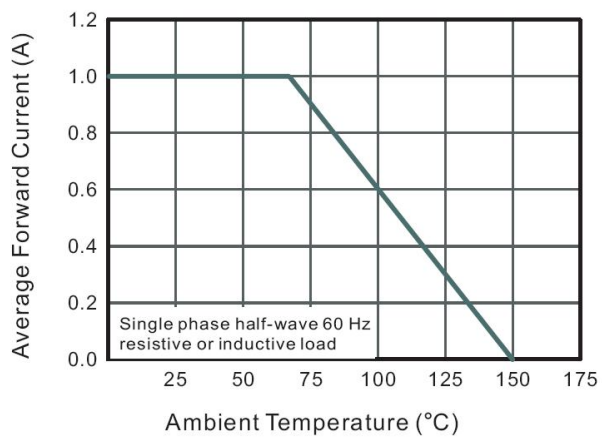
Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

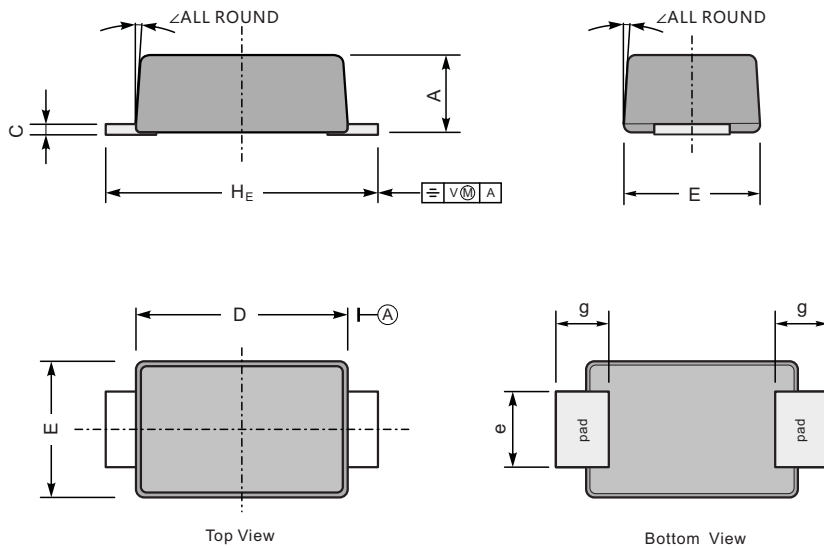
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	A 1	A 2	A 3	A 4	A 5	A 6	A 7	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_c = 125\text{ °C}$	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage at 1 A	V_F	1.1							V
Maximum DC Reverse Current $T_a = 25\text{ °C}$ at Rated DC Blocking Voltage $T_a = 125\text{ °C}$	I_R	5 50							μA
Typical Junction Capacitance ⁽¹⁾	C_j	11							pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	90							°C/W
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150							°C

Electrical Characteristic Curve



PACKAGE OUTLINE



UNIT		A	C	D	E	e	g	H _E	∠
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	
	min	35	4.7	102	67	31	28	138	

Marking

Type number	Marking code
1N4001W	A1
1N4002W	A2
1N4003W	A3
1N4004W	A4
1N4005W	A5
1N4006W	A6
1N4007W	A7